TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSVI)

2SK3561

Switching Regulator Applications

- Low drain-source ON resistance: $R_{DS (ON)} = 0.75 \Omega$ (typ.)
- High forward transfer admittance: |Y_{fs}| = 6.5 S (typ.)
- Low leakage current: $I_{DSS} = 100 \mu A (V_{DS} = 500 V)$
- Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C) Characteristics Symbol Rating Unit Drain-source voltage VDSS 500

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Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	500	У	
Gate-source voltage			V_{GSS}	±30	> v
Drain current	DC	(Note 1)	ΙD	8	
	Pulse	(t = 1 ms) (Note 1)	I _{DP}	32	A
Drain power dissipation (Tc = 25°C)		PD	40	$\langle \langle w \rangle \rangle$	
Single pulse avalanche energy (Note 2)		EAS	312	mJ	

Single pulse avalanche energy (Note 2)

Avalanche current

Repetitive avalanche energy (Note 3)

Channel temperature

EAS

312

mJ

Alan

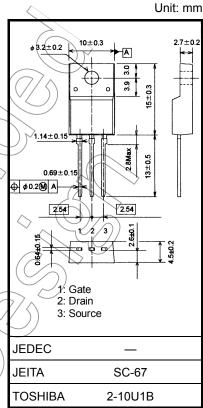
EAR

4

MJ

Channel temperature

Tstg



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

-55 to 150

°C

Thermal Characteristics

Storage temperature range

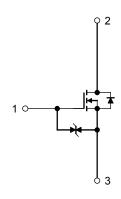
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	3.125	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}(\text{initial})$, L = 8.3 mH, $I_{AR} = 8 \text{ A}$, $R_G = 25 \Omega$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

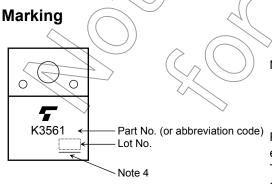


Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ
Gate-source breakdown voltage		V (BR) GSS	$I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$	±30	_		V
Drain cut-off current		I _{DSS}	V _{DS} = 500 V, V _{GS} = 0 V	_	_	100	μΑ
Drain-source bre	akdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	500	_		V
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0) }~	4.0	V
Drain-source ON resistance		R _{DS} (ON)	V _{GS} = 10 V, I _D = 4 A	>_	0.75	0.85	Ω
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 4 A	3.0	6.5		S
Input capacitance		C _{iss}		_	1050		
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	· —	10		pF
Output capacitan	Output capacitance			_	110		
Switching time	Rise time	t _r	10 V ID 4A VOUT VGS	-	26		
	Turn-on time	t _{on}	50 Ω RL = 50 Ω	_((45) —	20
	Fall time	t _f	V _{DD} ≈ 200 V	7	> 38		ns
	Turn-off time	t _{off}	Duty≤ 1%, t _w = 10 μs		130		
Total gate charge		Qg) —	28	_	
Gate-source charge		Qgs	$V_{DD} \simeq 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 8 \text{ A}$		16	_	nC
Gate-drain charge		Qgd		_	12		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1))) I _{DR}		_	_	8	Α
Pulse drain reverse current (Note 1)	IDRR	$(\langle // \rangle)$ –	_	_	32	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 8 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	tri	$I_{DR} = 8 \text{ A}, V_{GS} = 0 \text{ V},$	_	1200	_	ns
Reverse recovery charge	Qrr	dl _{DR} /dt = 100 A/μs	_	10	_	μС

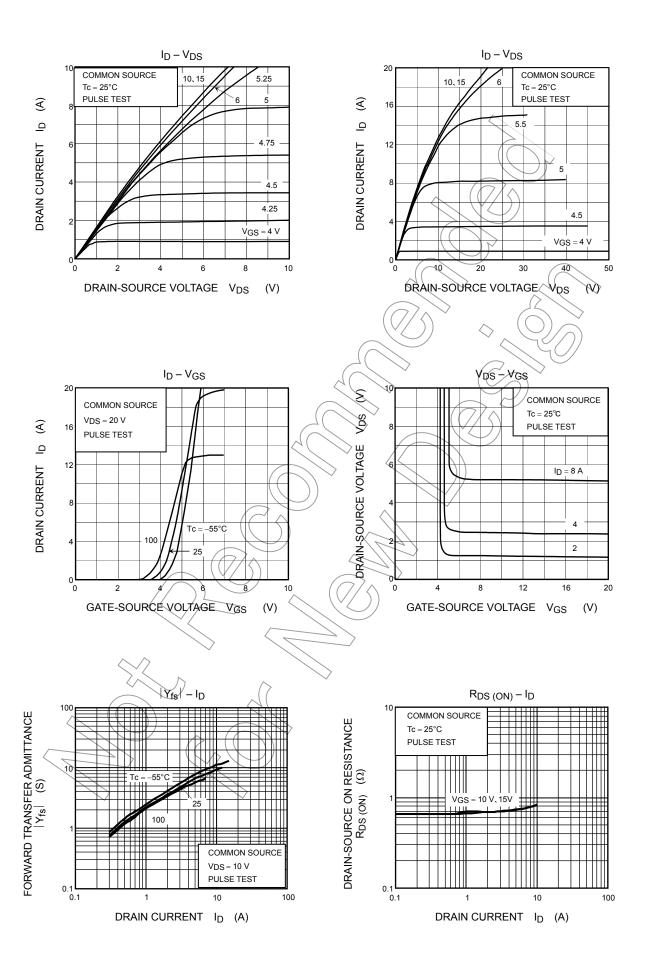


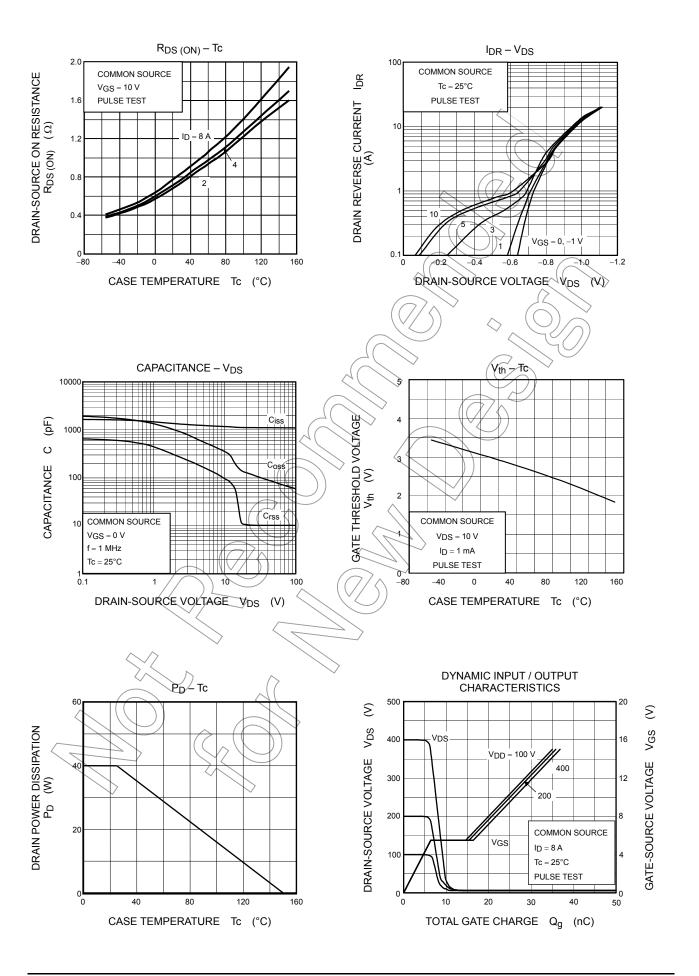
Note 4: A line under a Lot No. identifies the indication of product Labels.

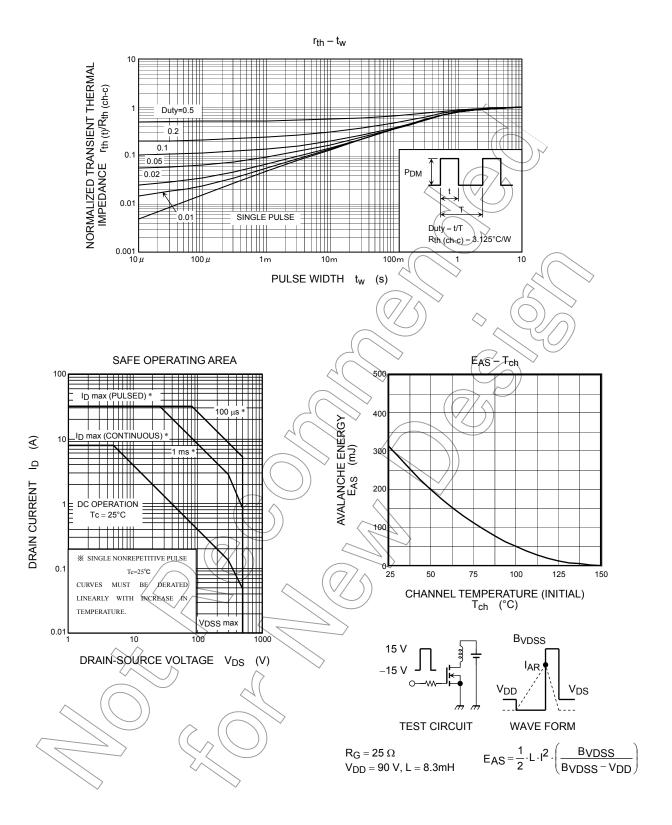
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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